High Voltage LED Series Chip on Board

LCoo6D-Gen.2

High efficacy COB LED package well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in •
- Simple assembly reduces manufacturing cost •
- Low thermal resistance •
- InGaN/GaN MQW LED with long time reliability •

Applications

- Spotlight / Downlight •
- LED Retrofit Bulbs
- Outdoor Illumination •





SAMSUNG

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1. Characteristics

a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	٥C	-
Storage Temperature	T _{stg}	-40 ~ +120	٥C	-
LED Junction Temperature	TJ	150	٥C	-
Case Temperature	Тс	115	٥C	
Forward Current	Ι _F	460	mA	-
Power Dissipation	P _D	17.2	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics $(I_F = 180 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C})$

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V_F)	V	YZ	31.8	34.6	37.5
Oslas Dandarias Index (D.)		5	80	-	-
Color Rendering Index (R _a)	-	7	90		
Thermal Resistance (junction to case point)	°C/W		-	1.48	-
Beam Angle	0		-	115	-
Nominal Power	W			6.2	

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_J = T_C = T_a = 85$ °C)
- 2) Samsung maintains measurement tolerance of: forward voltage = ± 5 %, CRI = ± 1
- 3) Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.

c) Luminous Flux Characteristics (I_F = 180 mA)

CRI (R _a)	Nominal	Flux	Flux @ T _J = 85 °C (lm)			
Min.	CCT (K)	Rank	Min.	Тур.	Max.	
	2700	D2	877	924	-	
	3000	D2	922	971	-	
	3500	D2	951	1001	-	
80	4000	D2	973	1024	-	
	5000	D2	979	1030	-	
	5700	D2	979	1030	-	
	6500	D2	967	1018	-	
	2700	D2	747	786	-	
	3000	D2	783	824	-	
90	3500	D2	810	853	-	
	4000	D2	827	870	-	
	5000	D2	830	874	-	

Notes:

1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature $(T_j = T_c = 85 \text{ °C}).$

2) Samsung maintains measurement tolerance of: Luminous flux = \pm 7 %, CRI = \pm 1

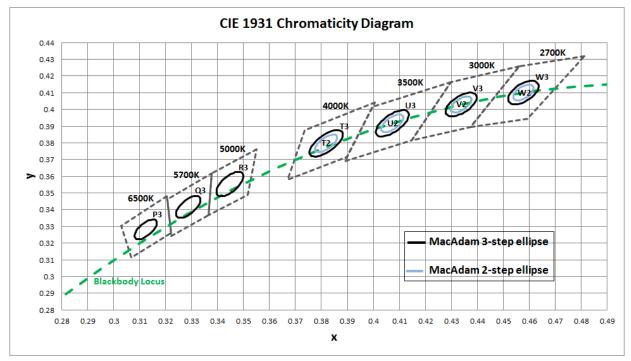
2. Product Code Information

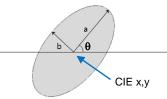
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S																	

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	А	
78	Form Factor	HD	СОВ
9	Lens Type	N	No lens
10	Wattage or Model	В	LC006D
11	Internal Code	2	
12	CRI & Sorting Temperature	5	Min. 80 (85°C)
12		7	Min. 90 (85°C)
13 14	Forward Voltage (V)	YZ	31.8~37.5
		w	2700K
		v	3000K
		U	3500K
15	CCT (K)	т	4000K
		R	5000K
		Q	5700K
		Р	6500K
16	MacAdam Step	2	MacAdam 2-step
		3	MacAdam 3-step
17 18	Luminous Flux (Lm)	D2	COB D-series Gen.2 level

a) Binning Structure ($I_F = 180 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C}$)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Flux Rank	Flux Range (Φ _v , lm)
	0700	SPHWHAHDNB25YZW2D2	\/ 7	W2	Do	077
	2700	SPHWHAHDNB25YZW3D2	YZ	W3	D2	877 ~
	3000	SPHWHAHDNB25YZV2D2	YZ	V2	D2	922 ~
	3000	SPHWHAHDNB25YZV3D2	ΤΖ	V3	D2	922 ~
	3500	SPHWHAHDNB25YZU2D2	YZ	U2	D2	951 ~
80	3300	SPHWHAHDNB25YZU3D2	12	U3	02	331 -
	4000	SPHWHAHDNB25YZT2D2	YZ	T2	D2	973 ~
	4000	SPHWHAHDNB25YZT3D2	12	Т3	02	313 ~
	5000	SPHWHAHDNB25YZR3D2	YZ	R2	D2	979 ~
	5700	SPHWHAHDNB25YZQ3D2	YZ	Q2	D2	979 ~
	6500	SPHWHAHDNB25YZP3D2	ΥZ	P2	D2	967 ~
	2700	SPHWHAHDNB27YZW2D2	YZ	W2	D2	747 ~
	2100	SPHWHAHDNB27YZW3D2	12	W3	02	
	3000	SPHWHAHDNB27YZV2D2	YZ	V2	D2	783 ~
		SPHWHAHDNB27YZV3D2	12	V3		100 10
	3500	SPHWHAHDNB27YZU2D2	····· YZ	U2	D2	810 ~
		SPHWHAHDNB27YZU3D2	12	U3	<u> </u>	010
	4000	SPHWHAHDNB27YZT2D2	YZ	T2	D2	827 ~
	+000	SPHWHAHDNB27YZT3D2	12	Т3	02	021 ~
	5000	SPHWHAHDNB27YZR3D2	ΥZ	R3	D2	830 ~





MacAdam Ellipse (W2, W3)									
Step	CIE x	CIE y							
2-step	0.4578	0.4101	53.70	0.0054	0.0028				
3-step	0.4578	0.4101	53.70	0.0081	0.0042				

MacAdam Ellipse (U2, U3)								
Step	CIE x	CIE y						
2-step	0.4073	0.3917	54.00	0.0062	0.0028			
3-step	0.4073	0.3917	54.00	0.0093	0.0041			

MacAdam Ellipse (R3)									
Step	Step CIE x CIE y θ a b								
3-step 0.3447 0.3553 59.62 0.0082 0.0035									

MacAdam Ellipse (P3)								
Step	Step CIE x CIE y θ a b							
3-step	0.3123	0.3282	58.5700	0.0067	0.0029			

MacAdam Ellipse (V2, V3) Step CIE x CIE y θ a b 2-step 0.4338 0.403 53.22 0.0056 0.0027 3-step 0.4338 0.4030 53.22 0.0083 0.0041

	MacAdam Ellipse (T2, T3)								
Step	CIE x	CIE y							
2-step	0.3818	0.3797	53.72	0.0063	0.0027				
3-step	0.3818	0.3797	53.72	0.0094	0.0040				

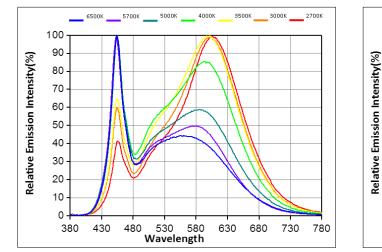
MacAdam Ellipse (Q3)						
Step	Step CIE x				b	
3-step	0.3287	0.3417	59.0950	0.0075	0.0032	

Note:

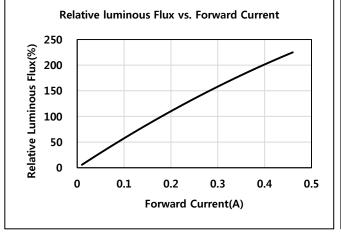
Samsung maintains measurement tolerance of: $Cx, Cy = \pm 0.005$

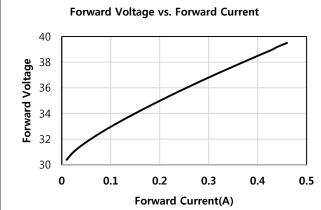
3. Typical Characteristics Graphs

a) Spectrum Distribution (I_F = 180 mA, T_J = 85 °C) CRI Ra 80+



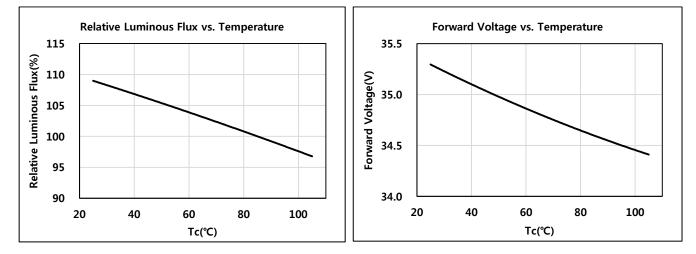
b) Forward Current Characteristics (T_J = 85 °C)





530 580 Wavelength

c) Temperature Characteristics (I_F = 180mA)



CRI Ra 90+

100

90

80

70 60

50

40

30

20

10

0 ·

380

430

480

5000К

4000K

3500к _____ 3000к _____ 2700к

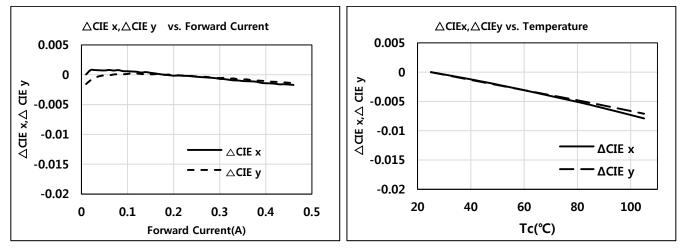
630

680

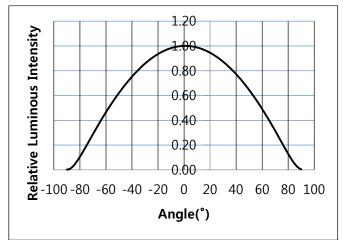
730

780

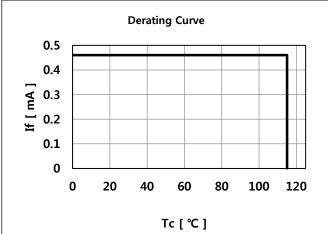
d) Color Shift Characteristics ($T_J = 85 \ ^{\circ}C$, $I_F = 180$ mA, CRI = 80+)



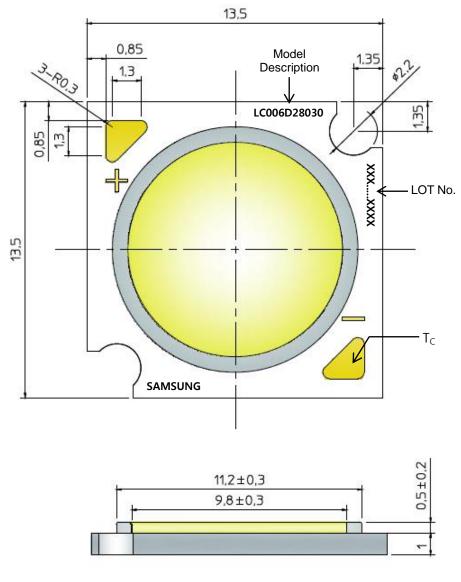




f) Derating Characteristics



4. Outline Drawing & Dimension



1. Unit: mm 2. Tolerance: ± 0.30 mm

ltem	Dimension	Tolerance	Unit
Length	13.5	±0.15	mm
Width	13.5	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	9.8	±0.30	mm

Note: Denoted product information above is only an example (LC006D28030 : LC006D, Gen2, CRI80+, 3000K)

5. Reliability Test Items & Conditions

a) Test Items

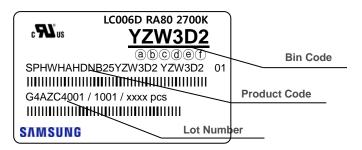
Test Item	Test Condition	Test Hour / Cycle	
High Temperature Humidity Life Test	60 °C, 90 % RH,, DC Derating, $\rm I_F$	1000 h	
High Temperature Life Test	85 °C, DC Derating, I _F	1000 h	
Low Temperature Life Test	-40 °C, DC, Derating I _F	1000 h	
High Temperature Storage	120 °C	1000 h	
Low Temperature Storage	-40 °C	1000 h	
Temperature Humidity Storage	60 °C, 90% RH	1000h	
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 30 min transfer power on/off each 5 min, DC Derating, $I_{\rm F}$ = max	100 cycles	
ESD (HBM)	R ₁ : 10 MΩ R ₂ : 1.5 kΩ C: 100 pF	5 times	
ESD (MM)	R ₁ : 10 MΩ R ₂ : 0 kΩ C: 200 pF	5 times	
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times	
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times	
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h	

b) Criteria for Judging the Damage

ltem	Symbol	Test Condition	Lin	Limit		
	Symbol	(T _c = 25 °C)	Min.	Max.		
Forward Voltage	V _F	I _F = 180 mA	L.S.L. * 0.9	U.S.L. * 1.1		
Luminous Flux	Φ _v	I _F = 180 mA	L.S.L * 0.7	U.S.L * 1.3		

6. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

- (a) (b): Forward Voltage bin (refer to page 11)
- ©d: Chromaticity bin (refer to page 9-10)
- (e) f): Luminous Flux bin (refer to page 6)

b) Lot Number

The lot number is composed of the following characters:

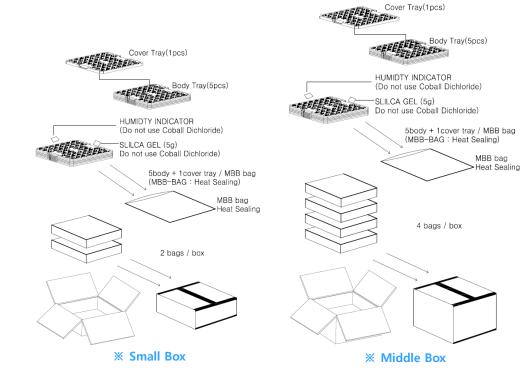


- 1 3456789 / 1abc / xxxx pcs
- (1) : Production site (S: Giheung, Korea, G: Tianjin, China)
- ② : 4 (LED)
- ③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
- (4) : Year (Z: 2015, A: 2016, B: 2017...)
- (5) : Month (1~9, A, B, C)
- 6789 : Day (1~9, A, B~V)
- (a)b)c) : Product serial number (001 ~ 999)

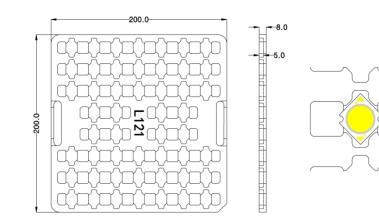
7. Packing Structure

	Max. quantity	Dimension(mm)			
Packing material	in pcs of COB	Length	Width	Height	Tolerance
Tray	50	200	200	8	1
Anti-Static Bag	250 (5 trays)	320	270	-	+/- 0.5
Outer Box (Small)	500 (2 bags)	225	225	65	5
Outer Box (Middle)	1000 (4 bags)	225	225	130	5

a) Packing Structure

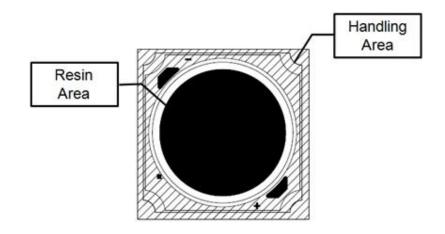


b) Tray



8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 6) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system. For more information, please refer to Application Note 'Mechanical & Thermal Guide for COB'.
- 9) In case of driving LEDs around the minimum current level (If_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



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